

# **S-8353/8354 Series**

# **STEP-UP, PWM CONTROL or PWM / PFM SWITCHABLE BUILT-IN TRANSISTOR SWITCHING REGULATOR**

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 $\overline{\odot}$  ABLIC Inc., 2002-2010 Rev.3.0\_02

The S-8353/8354 Series is a CMOS step-up switching regulator which mainly consists of a reference voltage source, an oscillation circuit, a power MOS FET, an error amplifier, a phase compensation circuit, a PWM control circuit (S-8353 Series) and a PWM / PFM switching control circuit (S-8354 Series).

The S-8353/8354 Series can configure the step-up switching regulator with an external coil, capacitor, and diode. In addition to the above features, the small package and low current consumption make the S-8353/8354 Series ideal for portable equipment applications requiring high efficiency.

The S-8353 Series realizes low ripple, high efficiency, and excellent transient characteristics due to its PWM control circuit whose duty ratio can be varied linearly from 0% to 83% (from 0% to 78% for 250 kHz models), an excellently designed error amplifier, and phase compensation circuits.

The S-8354 Series features a PWM / PFM switching controller that can switch the operation to a PFM controller with a duty ratio is 15% under a light load to prevent a decline in the efficiency due to the IC operating current.

# **Features**

- Low voltage operation: Startup at 0.9 V min.  $(I<sub>OUT</sub> = 1 mA)$  guaranteed
- Low current consumption : During operation 18.7 µA (3.3 V, 50 kHz, typ.) During shutdown:  $0.5 \mu A$  (max.)
- Duty ratio : Built-in PWM / PFM switching control circuit (S-8354 Series)
	- 15 % to 83 % (30 kHz and 50 kHz models)
	- 15 % to 78 % (250 kHz models)
- External parts : Coil, capacitor, and diode
- Output voltage : Selectable in 0.1 V steps between 1.5 V and 6.5 V (for  $V_{DD}$  /  $V_{OUT}$  separate types) Selectable in 0.1 V steps between 2.0 V and 6.5 V (for other than  $V_{DD} / V_{OUT}$  separate types)
- Output voltage accuracy :  $\pm 2.4\%$
- Oscillation frequency : 30 kHz, 50 kHz, and 250 kHz selectable
- Soft start function : 6 ms (50 kHz, typ.)
- Lead-free, Sn 100%, halogen-free**\*1**
- **\*1.** Refer to " **Product Name Structure**" for details.

# ■ Applications

- Power supplies for portable equipment such as digital cameras, electronic notebooks, and PDAs
- Power supplies for audio equipment such as portable CD / MD players
- Constant voltage power supplies for cameras, VCRs, and communication devices
- Power supplies for microcomputers

# ■ Packages

- SOT-23-3
- SOT-23-5
- SOT-89-3

# **Block Diagrams**

**(1) A, C and H Types (Without Shutdown Function)**





### **(2) A and H Types (With Shutdown Function)**





(3) D and J Types (V<sub>DD</sub> / V<sub>OUT</sub> Separate Type)



**Figure 3** 

# ■ Product Name Structure

The control system, product types, output voltage, and packages for the S-8353/8354 Series can be selected at the user's request. Please refer to the "**3. Product Name**" for the definition of the product name, "**4. Package**" regarding the package drawings and "**5. Product Name List**" for the full product names.

**Table 1**

### **1. Function List**

#### **(1) PWM Control Products**



#### **(2) PWM / PFM Switching Control Products**

### **Table 2**



### **2. Package and Function List by Product Type**



#### **Table 3**

### **3. Product Name**



**\*1.** Refer to the tape specifications.

**\*2.** Refer to the **Table 4** to **Table 8** in the "**5. Product Name List**".



**\*1.** Refer to the tape specifications.

**\*2.** Refer to the **Table 4** to **Table 8** in the "**5. Product Name List**".

#### **4. Package**



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#### **5. Product Name List**

#### **(1) S-8353 Series**

#### **Table 4**



#### **Table 5**



**Remark 1.** Please contact the ABLIC Inc. marketing department for products with an output voltage other than those specified above.

**2.** x: G or U

**3.**  $\Box$  $\Box$ : 2G or 1U

**4.** Please select products of environmental code = U for Sn 100%, halogen-free products.

#### **Table 6**



#### **(2) S-8354 Series**

#### **Table 7**



#### **Table 8**



**Remark 1.** Please contact the ABLIC Inc. marketing department for products with an output voltage other than those specified above.

**2.** x: G or U

**3.**  $\Box$  $\Box$ : 2G or 1U

**4.** Please select products of environmental code = U for Sn 100%, halogen-free products.

# **Pin Configurations**

SOT-23-3 Top view



**Figure 4**

SOT-23-5 Top view



#### **Table 9 A, C and H Types**  (Without shutdown function, V<sub>DD</sub> / V<sub>OUT</sub> non-separate type)



#### **Table 10 A and H Types**  (With shutdown function, V<sub>DD</sub> / V<sub>OUT</sub> non-separate type)



**Figure 5 \*1.** The NC pin indicates electrically open.

#### **Table 11 D and J Types**  (Without shutdown function, V<sub>DD</sub> / V<sub>OUT</sub> separate type)



**\*1.** The NC pin indicates electrically open.

# **Table 12 A and H Types**

(Without shutdown function, V<sub>DD</sub> / V<sub>OUT</sub> non-separate type)







**Figure 6**

**Table 13** 

# **Absolute Maximum Ratings**



**\*1.** With shutdown function

\*2. For V<sub>DD</sub> / V<sub>OUT</sub> separate type

**\*3.** When mounted on board

[Mounted board]

(1) Board size : 114.3 mm  $\times$  76.2 mm  $\times$  t1.6 mm

(2) Board name : JEDEC STANDARD51-7

**Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.**





**Figure 7 Power Dissipation of Packages** 

# **Electrical Characteristics**

# **(1) 50 kHz Product (A and D Types)**

**Table 14** 



External parts

Coil: CDRH6D28-101 of Sumida Corporation Diode: MA2Z748 (Shottky type) of Matsushita Electric Industrial Co., Ltd. Capacitor: F93 (16 V, 22  $\mu$ F tantalum type) of Nichicon Corporation  $V_{IN} = V_{OUT(S)} \times 0.6$  applied,  $I_{OUT} = V_{OUT(S)} / 250 \Omega$ With shutdown function :  $ON/\overline{OFF}$  pin is connected to  $V_{OUT}$ For  $V_{DD}$  /  $V_{OUT}$  separate type : VDD pin is connected to VOUT pin

- **Remark 1.** V<sub>OUT(S)</sub> specified above is the set output voltage value, and V<sub>OUT</sub> is the typical value of the actual output voltage.
	- **2.**  $V_{DD}$  /  $V_{OUT}$  separate type
		- A step-up operation is performed from  $V_{DD} = 0.8$  V. However, 1.8 V $\leq$ V<sub>DD</sub> $\leq$ 10 V is recommended stabilizing the output voltage and oscillation frequency. ( $V_{DD} \ge 1.8$  V must be applied for products with a set value of less than 1.9 V.)

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#### **(2) 30 kHz Product (C Type)**

![](_page_11_Picture_310.jpeg)

**Table 15** 

External parts

Coil: CDRH6D28-101 of Sumida Corporation

Diode: MA2Z748 (Shottky type) of Matsushita Electric Industrial Co., Ltd.

Capacitor: F93 (16 V, 22  $\mu$ F tantalum type) of Nichicon Corporation

 $V_{IN} = V_{OUT(S)} \times 0.6$  applied,  $I_{OUT} = V_{OUT(S)} / 250 \Omega$ 

**Remark**  $V_{\text{OUT}(S)}$  specified above is the set output voltage value, and  $V_{\text{OUT}}$  is the typical value of the actual output voltage.

# **STEP-UP, PWM CONTROL or PWM / PFM SWITCHABLE BUILT-IN TRANSISTOR SWITCHING REGULATOR** Rev.3.0\_02 **S-8353/8354 Series**

# **(3) 250 kHz Product (H and J Types)**

![](_page_12_Picture_376.jpeg)

External parts

Coil: CDRH6D28-220 of Sumida Corporation Diode: MA2Z748 (Shottky type) of Matsushita Electric Industrial Co., Ltd. Capacitor: F93 (16 V, 22  $\mu$ F tantalum type) of Nichicon Corporation  $V_{IN} = V_{OUT(S)} \times 0.6$  applied,  $I_{OUT} = V_{OUT(S)} / 250 \Omega$ With shutdown function :  $ON/\overline{OFF}$  pin is connected to  $V_{OUT}$ For  $V_{DD}$  /  $V_{OUT}$  separate type : VDD pin is connected to VOUT pin

- **Remark 1.** V<sub>OUT(S)</sub> specified above is the set output voltage value, and V<sub>OUT</sub> is the typical value of the actual output voltage.
	- **2.**  $V_{DD}$  /  $V_{OUT}$  separate type
		- A step-up operation is performed from  $V_{DD} = 0.8$  V. However, 1.8 V $\leq$ V<sub>DD</sub> $\leq$ 10 V is recommended stabilizing the output voltage and oscillation frequency. ( $V_{DD} \ge 1.8$  V must be applied for products with a set value of less than 1.9 V.)

# **Measurement Circuits**

![](_page_14_Figure_2.jpeg)

![](_page_14_Figure_3.jpeg)

- **\*1.** With shutdown function
- \*2. For V<sub>DD</sub> / V<sub>OUT</sub> separate type

### ■ Operation

#### **1. Switching Control Types**

#### **1. 1 PWM Control (S-8353 Series)**

The S-8353 Series is a DC-DC converter using a pulse width modulation method (PWM) and features low current consumption. In conventional PFM DC-DC converters, pulses are skipped when the output load current is low, causing a fluctuation in the ripple frequency of the output voltage, resulting in an increase in the ripple voltage. In the S-8353 Series, the switching frequency does not change, although the pulse width changes from 0% to 83% (78% for H and J type) corresponding to each load current. The ripple voltage generated from switching can thus be removed easily using a filter because the switching frequency is constant.

#### **1. 2 PWM / PFM Switching Control (S-8354 Series)**

The S-8354 Series is a DC-DC converter that automatically switches between a pulse width modulation method (PWM) and a pulse frequency modulation method (PFM), depending on the load current, and features low current consumption.

The S-8354 Series operates under PWM control with the pulse width duty changing from 15% to 83% (78% for H and J type) in a high output load current area. On the other hand, the S-8354 Series operates under PFM control with the pulse width duty fixed at 15% in a low output load current area, and pulses are skipped according to the load current. The oscillation circuit thus oscillates intermittently so that the resultant lower self current consumption can prevent a reduction in the efficiency at a low load current. The switching point from PWM control to PFM control depends on the external devices (coil, diode, etc.), input voltage, and output voltage. This series are an especially efficient DC-DC converter at an output current around 100 µA.

#### **2. Soft Start Function**

For this IC, a built-in soft start circuit controls the rush current and overshoot of the output voltage when the power is turned on or the  $ON/\overline{OFF}$  pin is set to "H" level.

### **3. ON/ OFF Pin (Shutdown Pin) (SOT-23-5 Package Products of A and H Types)**

 $ON/\overline{OFF}$  pin stops or starts step-up operation.

Setting the  $ON/\overline{OFF}$  pin to the "L" level stops operation of all the internal circuits and reduces the current consumption significantly.

DO NOT use the ON/OFF pin in a floating state because it has the structure shown in Figure 10 and is not pulled up or pulled down internally. DO NOT apply a voltage of between 0.3 V and 0.75 V to the ON/ $\overline{\text{OFF}}$  pin because applying such a voltage increases the current consumption. If the  $ON/\overline{OFF}$  pin is not used, connect it to the VOUT pin.

The  $ON/\overline{OFF}$  pin does not have hysteresis.

![](_page_16_Picture_143.jpeg)

![](_page_16_Picture_144.jpeg)

**\*1.** Voltage obtained by subtracting the voltage drop due to the DC resistance of the inductor and the diode forward voltage from  $V_{IN}$ .

![](_page_16_Figure_9.jpeg)

**Figure 10 ON/OFF** Pin Structure

#### **4. Operation**

The following are the basic equations [(1) through (7)] of the step-up switching regulator. (Refer to **Figure 11**.)

![](_page_17_Figure_3.jpeg)

**Figure 11 Step-Up Switching Regulator Circuit for Basic Equation** 

![](_page_17_Picture_268.jpeg)

L L dt

Integration of the equation (6) is as follows :

$$
I_{L} = I_{PK} - \left(\frac{V_{OUT} + V_{D} - V_{IN}}{L}\right) \cdot t
$$
 \n $(7)$ 

During t<sub>ON</sub>, the energy is stored in L and is not transmitted to V<sub>OUT</sub>. When receiving the output current ( $I_{\text{OUT}}$ ) from  $V_{\text{OUT}}$ , the energy of the capacitor (C<sub>L</sub>) is consumed. As a result, the pin voltage of C<sub>L</sub> is reduced, and goes to the lowest level after M1 is turned ON  $(t_{ON})$ . When M1 is turned OFF, the energy stored in L is transmitted through the diode to C<sub>L</sub>, and the voltage of C<sub>L</sub> rises rapidly.  $V_{\text{OUT}}$  is a time function, and therefore indicates the maximum value (ripple voltage (V<sub>P-P</sub>)) when the current flowing through into V<sub>OUT</sub> and load current ( $I_{\text{OUT}}$ ) match. Next, the ripple voltage is determined as follows.

 $I_{\text{OUT}}$  vs.  $t_1$  (time) from when M1 is turned OFF (after  $t_{\text{ON}}$ ) to when  $V_{\text{OUT}}$  reaches the maximum level :

$$
I_{OUT} = I_{PK} - \left(\frac{V_{OUT} + V_D - V_{IN}}{L}\right) \cdot t_1
$$
 (8)  
 
$$
\therefore t_1 = (I_{PK} - I_{OUT}) \cdot \left(\frac{L}{V_{OUT} + V_D - V_{IN}}\right)
$$
 (9)

When M1 is turned OFF ( $t_{\text{OFF}}$ ),  $I_L = 0$  (when the energy of the inductor is completely transmitted). Based on equation (7):

PK OFF OUT <sup>D</sup> IN I t V V V <sup>L</sup> (10)

When substituting equation (10) for equation (9) :

$$
t_1 = t_{OFF} - \left(\frac{I_{OUT}}{I_{PK}}\right) \cdot t_{OFF}
$$
 \n $\dots$  \n $\dots$ 

Electric charge  $\Delta Q_1$  which is charged in C<sub>L</sub> during  $t_1$ :

$$
\Delta Q_1 = \int_0^{t1} l_L dt = l_{PK} \cdot \int_0^{t1} dt - \frac{V_{OUT} + V_D - V_{IN}}{L} \cdot \int_0^{t1} t dt = l_{PK} \cdot t_1 - \frac{V_{OUT} + V_D - V_{IN}}{L} \cdot \frac{1}{2} t_1^2 \dots \tag{12}
$$

When substituting equation (12) for equation (9) :

 <sup>1</sup> PK OUT PK PK OUT <sup>1</sup> t 2 <sup>I</sup> <sup>I</sup> <sup>I</sup> <sup>I</sup> <sup>t</sup> 2 <sup>1</sup> Q1 <sup>I</sup> (13)

A rise in voltage ( $V_{\text{P-P}}$ ) due to  $\Delta Q_1$ :

<sup>1</sup> PK OUT L L <sup>1</sup> <sup>P</sup> <sup>P</sup> t 2 I I C 1 C <sup>∆</sup><sup>Q</sup> <sup>V</sup> (14)

When taking into consideration  $I_{\text{OUT}}$  to be consumed during  $t_1$  and the Equivalent Series Resistance (R<sub>ESR</sub>) of C<sub>L</sub>:

$$
V_{P-P} = \frac{\Delta Q_1}{C_L} = \frac{1}{C_L} \cdot \left(\frac{I_{PK} + I_{OUT}}{2}\right) \cdot t1 + \left(\frac{I_{PK} + I_{OUT}}{2}\right) \cdot R_{ESR} - \frac{I_{OUT} \cdot t_1}{C_L}
$$
 .................  
.................  
.................  
.................  
.................  
.................  
...

When substituting equation (11) for equation (15) :

ESR PK OUT L OFF PK 2 PK OUT <sup>P</sup> <sup>P</sup> R 2 I I C t 2I (I <sup>I</sup> ) <sup>V</sup> (16)

Therefore to reduce the ripple voltage, it is important that the capacitor connected to the output pin has a large capacity and a small  $R_{ESR}$ .

# ■ External Parts Selection

The relationship between the major characteristics of the step-up circuit and the characteristic parameters of the external parts is shown in **Figure 12**.

![](_page_19_Figure_3.jpeg)

**Figure 12 Relationship between Major Characteristics of Step-up Circuit and External Parts**

#### **1. Inductor**

The inductance value (L value) has a strong influence on the maximum output current ( $I_{OUT}$ ) and efficiency ( $\eta$ ). The peak current ( $I_{PK}$ ) increases by decreasing L value and the stability of the circuit improves and  $I_{OUT}$  increases. If L value is decreased, the efficiency falls causing a decline in the current drive capacity for the switching transistor, and  $I<sub>OUT</sub>$  decreases.

The loss of  $I_{PK}$  by the switching transistor decreases by increasing L and the efficiency becomes maximum at a certain L value. Further increasing L value decreases the efficiency due to the loss of the direct current resistance of the coil.  $I_{\text{OUT}}$  also decreases.

A higher oscillation frequency allows selection of a lower L value, making the coil smaller.

The recommended inductances are a 47  $\mu$ H to 220  $\mu$ H for A, C, and D types, a 10  $\mu$ H to 47  $\mu$ H for H and J types. Be careful of the allowable inductor current when choosing an inductor. Exceeding the allowable current of the inductor causes magnetic saturation, much lower efficiency and destruction of the IC chip due to a large current. Choose an inductor so that  $I_{PK}$  does not exceed the allowable current.  $I_{PK}$  in discontinuous mode is calculated by the following equation:

f L 2I (V <sup>V</sup> <sup>V</sup> ) <sup>I</sup> OSC OUT OUT <sup>D</sup> IN PK (A) (17)

 $f_{osc}$  = oscillation frequency,  $V_D \approx 0.4$  V.

#### **2. Diode**

Use an external diode that meets the following requirements :

- Low forward voltage :  $V_F < 0.3$  V
- High switching speed : 50 ns max.
- Reverse voltage :  $V_{\text{OUT}} + V_F$  or more
- Current rate :  $I_{PK}$  or more

### 3. Capacitor (C<sub>IN</sub>, C<sub>L</sub>)

A capacitor on the input side  $(C_{\text{IN}})$  improves the efficiency by reducing the power impedance and stabilizing the input current. Select a  $C_{\text{IN}}$  value according to the impedance of the power supply used.

A capacitor on the output side  $(C_L)$  is used for smoothing the output voltage. For step-up types, the output voltage flows intermittently to the load current, so step-up types need a larger capacitance than step-down types. Therefore, select an appropriate capacitor in accordance with the ripple voltage, which increases in case of a higher output voltage or a higher load current. The capacitor value should be 10  $\mu$ F or more.

Select an appropriate capacitor the equivalent series resistance ( $R_{ESR}$ ) for stable output voltage. The stable voltage range in this IC depends on the  $R_{FSR}$ . Although the inductance value (L value) is also a factor, an  $R_{FSR}$  of 30 to 500 m $\Omega$  maximizes the characteristics. However, the best R<sub>ESR</sub> value may depend on the L value, the capacitance, the wiring, and the applications (output load). Therefore, fully evaluate the  $R_{ESR}$  under the actual operating conditions to determine the best value.

Refer to the "**1. Example of Ceramic Capacitor Application**" (**Figure 16**) in the " **Application Circuit**" for the circuit example using a ceramic capacitor and the external resistance of the capacitor  $(R_{ESR})$ .

#### 4. V<sub>DD</sub> / V<sub>OUT</sub> Separate Type (D and J Types)

The D and J types provides separate internal circuit power supply (VDD pin) and output voltage setting pin (VOUT pin) in the IC, making it ideal for the following applications.

- (1) When changing the output voltage with external resistance.
- (2) When outputting a high voltage within the operating voltage (10 V).

Choose the products in the **Table 18** according to the applications (1) or (2) above.

Output voltage $(V_{\text{CC}})$	1.8 V $\leq$ V <sub>CC</sub> $<$ 5 V	$5 V \leq V_{CC} \leq 10 V$
S-835xx18	Yes	
S-835xx50		Yes
Connection to VDD pin	$\rm V_{\rm IN}$ or $\rm V_{\rm CC}$	V ini

**Table 18** 

- Cautions 1. This IC starts a step-up operation at  $V_{DD} = 0.8$  V, but set 1.8  $\leq V_{DD} \leq 10$  V to stabilize the output **voltage and frequency of the oscillator. (Input a voltage of 1.8 V or more at the VDD pin for all products with a setting less than 1.9 V.) An input voltage of 1.8 V or more at the VDD pin allows connection of the VDD pin to either the input voltage VIN pin or output VOUT pin.** 
	- 2. Choose external resistors  $R_A$  and  $R_B$  so as to not affect the output voltage, considering that there **is impedance between the VOUT pin and VSS pin in the IC chip. The internal resistance between the VOUT pin and VSS pin is as follows :** 
		- **(1) S-835xx18 : 2.1 M** $\Omega$  **to 14.8 M** $\Omega$
		- **(2) S-835xx20 : 1.4 MΩ to 14.8 MΩ**
		- **(3) S-835xx30 : 1.4 MΩ to 14.2 MΩ**
		- **(4) S-835xx50 : 1.4 MΩ to 12.1 MΩ**
	- 3. Attach a capacitor  $(C_c)$  in parallel to the  $R_A$  resistance when an unstable event such as oscillation of the output voltage occurs. Calculate C<sub>c</sub> using the following equation :

$$
C_{C} [F] = \frac{1}{2 \cdot \pi \cdot R_{A} \cdot 20 \text{ kHz}}
$$

### **Standard Circuits**

**(1) S-8353AxxMA / UA, S-8353CxxMA, S-8353HxxMA/UA, S-8354AxxMA/UA, S-8354CxxMA, S-8354HxxMA / UA** 

![](_page_21_Figure_3.jpeg)

**Remark** The power supply for the IC chip is from the VOUT pin.

**Figure 13** 

#### **(2) S-8353AxxMC, S-8353HxxMC, S-8354AxxMC, S-8354HxxMC**

![](_page_21_Figure_7.jpeg)

**Remark** The power supply for the IC chip is from the VOUT pin.

**Figure 14** 

#### SD  $\Gamma$ Ō Ŏ ਹੋ CONT VDD  $\mathbf{L}$ ♠ IC internal  $C<sub>C</sub>$ Oscillation circuit power  $\lessgtr R_A$ ∮ ⋠ **supply** <u>لو</u>  $V_{IN}$   $C_{IN}$ PWM control circuit  $^{+}$  $^{+}$  $\tilde{+}$ or PWM / PFM ⊫  $\equiv$  $\equiv$ switching control  $\overline{a}$ ⋚ VOUT circuit ≷R⊧ Soft start built-in Phase  $\frac{1}{\sqrt{2}}$ compensating reference power VSS ଭ supply circuit 777 ╫

#### **(3) S-8353DxxMC, S-8353JxxMC, S-8354DxxMC, S-8354JxxMC**

![](_page_22_Figure_3.jpeg)

#### **Figure 15**

**Caution The Above connection diagram will not guarantee successful operation. Perform through evaluation using the actual application to set the constant.** 

 $C_{L}$ 

# ■ Precautions

- Mount external capacitors, diodes, and coils as close as possible to the IC. Especially, mounting the output capacitor (capacitor between VDD pin and VSS pin for V<sub>DD</sub> / V<sub>OUT</sub> separate type) in the power supply line of the IC close to the IC can enable stable output characteristics. If it is impossible, it is recommended to mount and wire a ceramic capacitor of around  $0.1 \text{ uF}$  close to the IC.
- Characteristics ripple voltage and spike noise occur in IC containing switching regulators. Moreover rush current flows at the time of a power supply injection. Because these largely depend on the coil, the capacitor and impedance of power supply used, fully check them using an actually mounted model.
- Make sure that the dissipation of the switching transistor (especially at a high temperature) does not exceed the allowable power dissipation of the package.
- The performance of this IC varies depending on the design of the PCB patterns, peripheral circuits and external parts. Thoroughly test all settings with your device. The recommended external part should be used wherever possible, but if this is not possible for some reason, contact an ABLIC Inc. sales person.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- ABLIC Inc. claims no responsibility for any and all disputes arising out of or in connection with any infringement of the products including this IC upon patents owned a third party.

# **Application Circuits**

#### **1. Using Ceramic Capacitor Example**

When using small R<sub>ESR</sub> parts such as ceramic capacitors for the output capacitance, mount a resistor (R<sub>1</sub>) corresponding to the  $R_{ESR}$  in series with the ceramic capacitor  $(C_L)$  as shown in **Figure 16**.

 $R_1$  differs depending on L value, the capacitance, the wiring, and the application (output load).

The following example shows a circuit using R<sub>1</sub> = 100 m $\Omega$ , output voltage = 3.3 V, output load = 100 mA and its characteristics.

![](_page_24_Figure_6.jpeg)

**Figure 16 Using Ceramic Capacitor Circuit Example** 

![](_page_24_Picture_118.jpeg)

![](_page_24_Picture_119.jpeg)

**Caution The Above connection diagram and constant will not guarantee successful operation. Perform through evaluation using the actual application to set the constant.** 

### **2. Output Characteristics of The Using Ceramic Capacitor Circuit Example**

The data of the step-up characteristics (a) Output current  $(I_{\text{OUT}})$  vs. Efficiency (n) characteristics, (b) Output current ( $I_{\text{OUT}}$ ) vs. Output voltage ( $V_{\text{OUT}}$ ) characteristics, (c) Output Current ( $I_{\text{OUT}}$ ) vs. Ripple voltage ( $V_r$ ) under conditions in **Table 19** is shown below.

![](_page_25_Figure_3.jpeg)

![](_page_25_Figure_4.jpeg)

# **Characteristics (Typical Data)**

# 1. Example of Major Temperature characteristics (Ta = -40°C to +85°C, V<sub>OUT</sub> = 3.3 V)

![](_page_26_Figure_3.jpeg)

![](_page_26_Figure_4.jpeg)

![](_page_26_Figure_5.jpeg)

### (2) Current Consumption 2 (I<sub>SS2</sub>) vs. Temperature (Ta)

![](_page_26_Figure_7.jpeg)

![](_page_26_Figure_8.jpeg)

(3) Current Consumption at Shutdown (I<sub>SSS</sub>) vs. Temperature (Ta)

![](_page_26_Figure_10.jpeg)

![](_page_26_Figure_12.jpeg)

(4) Switching Current (I<sub>SW</sub>) vs. Temperature (Ta) (5) Switching Transistor Leakage Current (I<sub>SWQ</sub>) vs. Temperature (Ta)

 $f_{\text{OSC}}$  = 250 kHz  $f_{\text{OSC}}$  = 250 kHz 0.2 0.4  $\frac{2}{3}$  0.6<br> $\frac{8}{3}$  0.4 0.8 1.0  $-40$   $-20$  0 20 40 60 80 100 Ta $[°C]$ 

**ABLIC Inc.** 

(6) Oscillation Frequency (f<sub>osc</sub>) vs. Temperature (Ta)

![](_page_27_Figure_2.jpeg)

**(7) Maximum Duty Ratio (MaxDuty) vs. Temperature (Ta)** 

![](_page_27_Figure_4.jpeg)

**(8) PWM / PFM Switching Duty Ratio (PFMDuty) vs. Temperature (Ta) (S-8354 Series)**

![](_page_27_Figure_6.jpeg)

![](_page_27_Figure_7.jpeg)

![](_page_27_Figure_8.jpeg)

![](_page_27_Figure_9.jpeg)

![](_page_27_Figure_10.jpeg)

(9) ON/ OFF Pin Input Voltage "H" (V<sub>SH</sub>) vs. **Temperature (Ta)** 

![](_page_27_Figure_12.jpeg)

(11)  $ON/\overline{OFF}$  Pin Input Voltage "L" 2 (V<sub>SL2</sub>) vs. **Temperatuer (Ta)** 

![](_page_27_Figure_14.jpeg)

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#### (12) Soft Start Time (t<sub>ss</sub>) vs. Temperature (Ta)

![](_page_28_Figure_2.jpeg)

![](_page_28_Figure_4.jpeg)

(15) Output Voltage (V<sub>OUT</sub>) vs. Temperature (Ta)

![](_page_28_Figure_6.jpeg)

![](_page_28_Figure_7.jpeg)

(13) Operation Start Voltage (V<sub>ST1</sub>) vs. Temperature (Ta) (14) Oscillation Start Voltage (V<sub>ST2</sub>) vs. Temperature (Ta)

![](_page_28_Figure_9.jpeg)

![](_page_28_Figure_10.jpeg)

### **2. Examples of Major Power Supply Dependence Characteristics (Ta = 25C)**

(1) Current Consumption 1 (I<sub>SS1</sub>) vs. Power Supply Voltage (V<sub>DD</sub>), **Current Consumption 2 (I<sub>SS2</sub>) vs. Power Supply Voltage** 

(V<sub>DD</sub>)

![](_page_29_Figure_4.jpeg)

3.1

 $\frac{4}{v_{DD} [V]}$  6

 $\frac{4}{V_{DD}$  [V]  $^6$ 

 $3.0<sup>L</sup>$ 

3.1

**3. Output Waveforms (V<sub>IN</sub> = 1.98 V)** 

![](_page_30_Figure_2.jpeg)

t  $[2 \mu s / div]$ 

**4. Examples of Transient Response Characteristics (Ta 25C, 250 kHz, S-8354H33)** 

**(1) Power-On**  $(V_{1N}: 0 V \rightarrow 2.0 V)$ 

![](_page_31_Figure_3.jpeg)

![](_page_31_Figure_4.jpeg)

![](_page_31_Figure_5.jpeg)

![](_page_31_Figure_6.jpeg)

![](_page_31_Figure_7.jpeg)

![](_page_31_Figure_8.jpeg)

(4) Input Voltage Fluctuations (I<sub>OUT</sub> = 50 mA)

![](_page_31_Figure_10.jpeg)

![](_page_31_Figure_11.jpeg)

![](_page_31_Figure_12.jpeg)

![](_page_31_Figure_13.jpeg)

### ■ Reference Data

Reference data is provided to determine specific external components. Therefore, the following data shows the characteristics of the recommended external components selected for various applications.

#### **1. External Parts for Reference Data**

**Table 20 Efficiency vs. Output Current Characteristics and Output Voltage vs. Output Current Characteristics for External Parts** 

Condition	<b>Product Name</b>	Oscillation frequency	Output voltage	Control system	Inductor	Diode	Output capacitor
	S-8353H50MC	250 kHz	5.0V	<b>PWM</b>	CDRH8D28-220	MA2Z748	F93 (16 V, 47 µF)
2	S-8353H50MC	250 kHz	5.0V	<b>PWM</b>	CDRH5D28-220		F93 (6.3 V, 22 $\mu$ F)
3	S-8353H50MC	250 kHz	5.0V	<b>PWM</b>	CXLP120-220		F92 (6.3 V, 47 $\mu$ F)
4	S-8354A50MC	50 kHz	5.0V	PWM / PFM	CDRH8D28-101		F93 (6.3 V, 22 $\mu$ F)
5	S-8354A50MC	50 kHz	5.0V	PWM / PFM	CXLP120-470		F92 (6.3 V, 47 $\mu$ F)
6	S-8353A50MC	50 kHz	5.0V	<b>PWM</b>	CDRH8D28-101		F93 (6.3 V, 22 $\mu$ F)
	S-8353A50MC	50 kHz	5.0V	<b>PWM</b>	CXLP120-470		F92 (6.3 V, 47 µF)
8	S-8353A33MC	50 kHz	3.3V	<b>PWM</b>	CDRH8D28-101		F93 (6.3 V, 22 $\mu$ F)

The properties of the external parts are shown below.

![](_page_32_Picture_248.jpeg)

![](_page_32_Picture_249.jpeg)

**\*1.** Direct current resistance

**\*2.** Maximum allowable current

**\*3.** Forward voltage

**\*4.** Forward current

**Caution The values shown in the characteristics column of Table 21 above are based on the materials provided by each manufacture. However, consider the characteristics of the original materials when using the above products.** 

#### 2. Output Current (I<sub>OUT</sub>) vs. Efficiency (η) Characteristics, Output Current (I<sub>OUT</sub>) vs. Output Voltage **(VOUT) Characteristics**

The following shows the actual (a) Output current ( $I_{\text{OUT}}$ ) vs. Efficiency ( $\eta$ ) characteristics and (b) Output current ( $I_{\text{OUT}}$ ) vs. Output voltage (V<sub>OUT</sub>) characteristics under the conditions of No. 1 to 8 in Table 20.

#### **Condition 1 S-8353H50MC**

![](_page_33_Figure_4.jpeg)

![](_page_33_Figure_5.jpeg)

![](_page_33_Figure_6.jpeg)

**Condition 3 S-8353H50MC** 

![](_page_33_Figure_8.jpeg)

![](_page_33_Figure_9.jpeg)

![](_page_33_Figure_10.jpeg)

![](_page_33_Figure_11.jpeg)

![](_page_33_Figure_12.jpeg)

![](_page_33_Figure_13.jpeg)

(a) Output current ( $I_{OUT}$ ) vs. Efficiency ( $\eta$ ) (b) Output current ( $I_{OUT}$ ) vs. Output voltage ( $V_{OUT}$ )

![](_page_33_Figure_15.jpeg)

(a) Output current  $(I<sub>OUT</sub>)$  vs. Efficiency (n) (b) Output current  $(I<sub>OUT</sub>)$  vs. Output voltage  $(V<sub>OUT</sub>)$ 

![](_page_33_Figure_17.jpeg)

![](_page_34_Figure_1.jpeg)

![](_page_34_Figure_2.jpeg)

![](_page_34_Figure_3.jpeg)

![](_page_34_Figure_4.jpeg)

![](_page_34_Figure_5.jpeg)

![](_page_34_Figure_6.jpeg)

![](_page_34_Figure_7.jpeg)

![](_page_34_Figure_8.jpeg)

#### 3. Output Current (I<sub>OUT</sub>) vs. Ripple Voltage (V<sub>r</sub>) Characteristics

The following shows the actual Output current  $(I_{\text{OUT}})$  vs. Ripple voltage (V<sub>c</sub>) characteristics and (b) Output current  $(I<sub>OUT</sub>)$  vs. Output voltage ( $V<sub>OUT</sub>$ ) characteristics under the conditions of No. 1 to 8 in **Table 20**.

![](_page_35_Figure_3.jpeg)

![](_page_35_Figure_4.jpeg)

![](_page_35_Figure_5.jpeg)

![](_page_35_Figure_7.jpeg)

![](_page_35_Figure_8.jpeg)

![](_page_35_Figure_9.jpeg)

![](_page_35_Figure_11.jpeg)

![](_page_35_Figure_12.jpeg)

![](_page_35_Figure_13.jpeg)

**Condition 5 S-8354A50MC Condition 6 S-8353A50MC** 

![](_page_35_Figure_15.jpeg)

![](_page_35_Figure_17.jpeg)

![](_page_36_Figure_0.jpeg)

![](_page_36_Figure_1.jpeg)

![](_page_36_Figure_2.jpeg)

No. MP003-A-P-SD-1.2

![](_page_36_Picture_26.jpeg)

![](_page_37_Figure_0.jpeg)

![](_page_37_Figure_1.jpeg)

![](_page_37_Figure_2.jpeg)

Feed direction

No. MP003-A-C-SD-2.0

![](_page_37_Picture_41.jpeg)

![](_page_38_Figure_0.jpeg)

![](_page_39_Figure_0.jpeg)

![](_page_39_Figure_1.jpeg)

![](_page_39_Figure_2.jpeg)

No. MP003-C-P-SD-1.1

 $\hat{\mathcal{A}}$ 

![](_page_39_Picture_26.jpeg)

![](_page_40_Figure_0.jpeg)

![](_page_41_Figure_0.jpeg)

![](_page_42_Figure_0.jpeg)

![](_page_42_Figure_1.jpeg)

![](_page_42_Figure_2.jpeg)

No. MP005-A-P-SD-1.3

![](_page_42_Picture_23.jpeg)

![](_page_43_Figure_0.jpeg)

![](_page_44_Figure_0.jpeg)

![](_page_45_Figure_0.jpeg)

![](_page_46_Figure_0.jpeg)

![](_page_47_Figure_0.jpeg)

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![](_page_48_Picture_17.jpeg)

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